Page 1 of 1 Atty. Docket No. Form PTO-1449 (modified) Serial No. 2000.108400/DE0349 10/649,051 List of Patents and Publications for **Applicant** Karsten Wieczorek, Rolf Geilenkeuser and Jörg-Oliver Weidner INFORMATION DISCLOSURE STATEMENT Filing Date: Group: (Use several sheets if necessary) August 27, 2003 2811 **Foreign Patent Documents** Other Art U.S. Patent Documents See Page 1 See Page 1 See Page 1

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Exam. Init.	Ref. Des.	Document Number	Date	Name	Class	Sub Class	Filing Date of App.
(D)	A1	6,472,233 B1	10/29/02	Ahmed et al.	438	14	
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	А3 -						,
	A4						
	A5 -						

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Exam.	Ref. Des.	Document Number	Date	Country	Class	Sub Class	Translation Yes/No
as	B1	DE 100 10 285 A1	9/13/01	Germany	H01L	23/544	No
	B2				===		
	B3 /						

Other Art (Including Author, Title, Date Pertinent Pages, Etc.)

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AS.	C1	Kim et al., "Breakdown Phenomena in MIS Structure," Proc. Of 3 rd Int'l Conf. on Properties and Application of Dielectric Materials, Tokyo, Japan, pp. 164-168, July 8-12, 1991.				
El.	C2	Shanware et al., "Reliability evaluation of HiSiON gate dielectric film with 12.8 Å SiO ₂ equivalent thickness," <i>IEEE</i> , pp. 6.6.1-6.6.4, 2001.				
28	C3	Abadeer et al., "Key measurements of ultrathin gate dielectric reliability and in-line monitoring," IBM J. Res. Develop., 43:407-16, 1999.				

EXAMINER; **DATE CONSIDERED:**

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